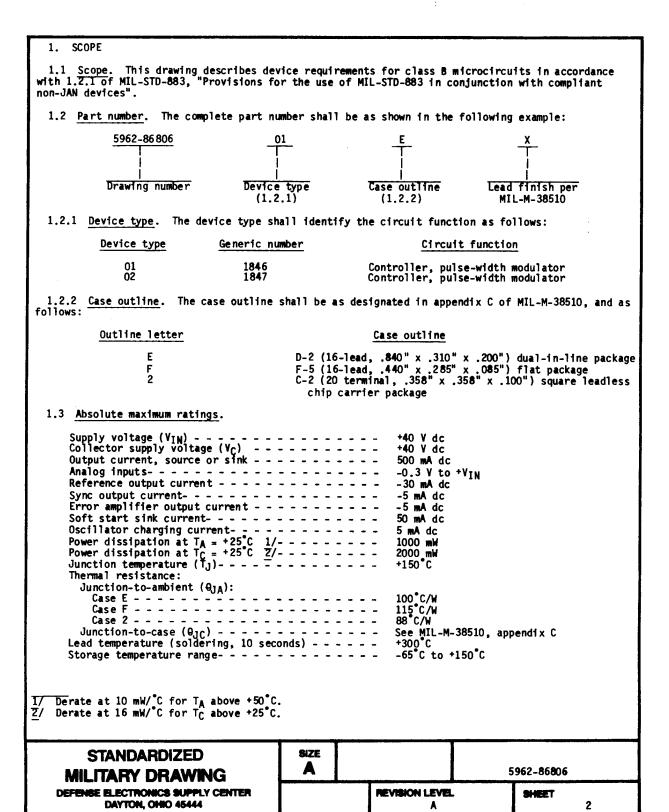
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1.4	Recommended	operating	conditions.

### 2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

**SPECIFICATION** 

**MILITARY** 

MIL-M-38510

- Microcircuits, General Specification for.

**STANDARD** 

MILITARY

MIL-STD-883

Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

### 3. REQUIREMENTS

- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 <u>Design</u>, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
  - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
  - 3.2.2 Block diagram. The block diagram shall be as specified on figure 2.
  - 3.2.3 Case outline. The case outline shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full ambient operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

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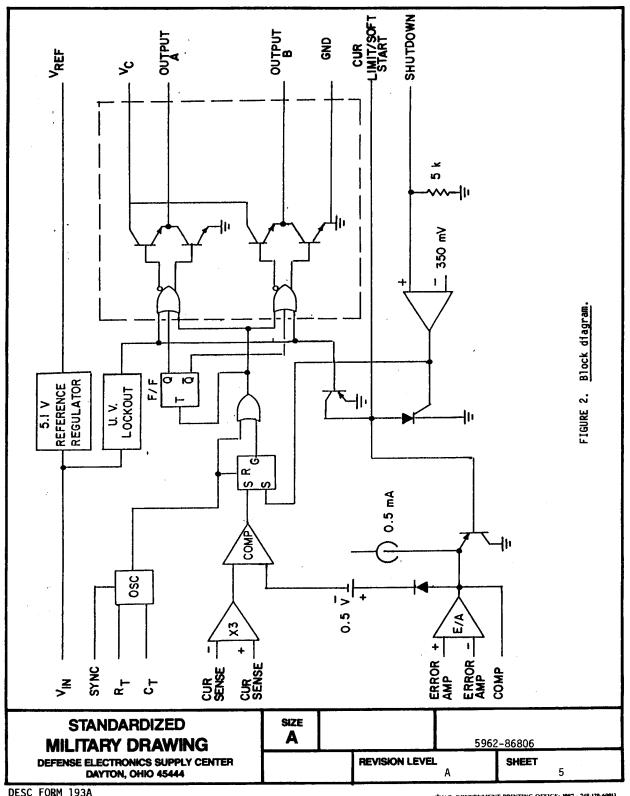
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Device type	01 ar	nd 02
Case outlines	E and F	2
Terminal   number	Termina 	i symbol
1	CUR. LIMIT/SOFTSTART	NC
2	VREF	CUR. LIMIT/SOFTSTART
3	(-) CUR. SENSE	V <sub>REF</sub>
4	(+) CUR. SENSE	(-) CUR. SENSE
5	(+) ERROR AMP	(+) CUR. SENSE
6	(-) ERROR AMP	NC
7	COMPENSATION	(+) ERROR AMP
8	CT	(-) ERROR AMP
9	R <sub>T</sub>	COMPENSATION
10	SYNC	C <sub>T</sub>
11	OUTPUT A	NC
12	GROUND	R <sub>T</sub>
13	V <sub>C</sub>	SYNC
14	OUTPUT B	OUTPUT A
15	V <sub>IN</sub>	GROUND
16	SHUTDOWN	NC
17	<del></del>	VC
18		OUTPUT B
19		VIN
20		SHUTDOWN

NC = no connection

FIGURE 1. Terminal connections.

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TA	BLE I. El	ectrical performance character	ristics.		-	
Test	Symbol		Group A		nits Max	Unit
Reference section						<del>i</del>
Output voltage	v <sub>o</sub>	T <sub>A</sub> = +25°C I <sub>O</sub> = 1 mA		5.05	5.15	V dc
Line regulation	RLINE	8 V <u>&lt;</u> V <sub>IN</sub> <u>&lt;</u> 40 V	1, 2, 3	-20	20	mV do
Load regulation	RLOAD	$I-10$ mA $\leq$ $I_{L}$ $\leq$ $-1$ mA	1, 2, 3	-15	15	mV dc
Total output variation 2/		  Line, load, and temperature		5.00	5.20	V dc
Short circuit output	Ios	VREF = 0 V	1, 2, 3	-1	-10	mA dc
Oscillator section				İ		<u> </u>
Initial accuracy		T <sub>A</sub> = +25°C  R <sub>T</sub> = 10 kΩ  C <sub>T</sub> = 4700 pF	4	39	47	kHz
Frequency change with voltage	ge Afosc	8 V <u>&lt;</u> V <sub>I</sub> <u>&lt;</u> 40 V	4, 5, 6	-2.0	2.0	%
Sync output voltage High level Low level	V <sub>SOL</sub>		1, 2, 3	3.9	2.7	V dc
Sync input voltage High level Low level	VSIL VSIH	C <sub>T</sub> = 0 V	1, 2, 3	3.9	2.5	V dc
Sync input current		Sync voltage = 5.25 V C <sub>T</sub> = 0 V	1, 2, 3	<u> </u>	1.5	mA dc
Error amplifier section	<u> </u>		1	1		
Input offset voltage	V <sub>IO</sub>		1, 2, 3		5.0	mV dc
Input bias current	IIB		1, 2, 3  -	1.0		μ <b>A</b> dc
See footnotes at end of table					<u>'</u>	i
STANDARDIZED MILITARY DRAWI		SIZE A		0.055		
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TABLE I. <u>E</u>	lectrica	l performance characteristics -	Continued.	:		
Test	Symbo1	Conditions 1/	  Group A	ĺ	mits	Unit
		Conditions 1/ -55°C < TA < +125°C	subgroups	Min	Max	
Error amplifier section - Continued.						
Input offset current	110		1, 2, 3	  -250	250	nA dc
Open loop voltage gain	Ays	$\Delta V_0 = 1.2 \text{ V to 3 V V}_{CM} = 2 \text{ V}$	4, 5, 6	80		dB
Unity gain bandwidth <u>2</u> /	G <sub>BW</sub>	T <sub>A</sub> = +25°C	4	0.7		   MHz 
Common mode rejection ratio	  CMRR 	0 V < V <sub>CM</sub> < 38 V V <sub>IN</sub> = 40 V	4, 5, 6	75		l dB
Power supply rejection ratio	PSRR	8 V <u>&lt;</u> V <sub>IN</sub> <u>&lt;</u> 40 V	4, 5, 6	80		dB
Output sink current (COMPENSATION pin)	ISINK	-15 mV <u>&lt; V<sub>ID</sub> &lt;</u> -5 V	1, 2, 3	2.0		mA dc
		VCOMP pin = 1.2 V	1		<u> </u>	<u> </u>
Output source current (COMPENSATION pin)	1	15 mV <u>&lt;</u> V <sub>ID</sub> <u>&lt;</u> 5 V	1, 2, 3		-0.4	mA dc
	! !	VCOMP pin = 2.5 V	1 1		 	
High level output voltage	I VOH	$ R_L  = (COMP) 15 k\Omega$	1, 2, 3	4.3	 	V dc
Low level output voltage	v <sub>OL</sub>	R <sub>L</sub> = (COMP) 15 kΩ	1, 2, 3		1.0	V dc
Current sense amplifier section		V(-CUR SENSE pin) = 0 V				
Amplifier gain	Αγ	V(CUR LIM/SS pin) open 3/4/	4, 5, 6	2.5	3.15	V dc
Maximum differential input signal (pos and neg current sense pin voltages)	VIDIFF	$V$ (CUR LIM/SS pin) open $3/$ $R_L$ = (COMP pin) = 15 k $\Omega$	1, 2, 3	1.1		V dc
Input offset voltage	۷ <sub>10</sub>	V(CUR LIM/SS pin) = 0.5 V COMP pin open 3/	1, 2, 3	-25	25	mV dc
See footnotes at end of table.			·			
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**MILITARY DRAWING** 

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Test	Symbol	Conditions 1/ -55°C < T <sub>A</sub> < +125°C	Group A subgroup:	1	Max	_ Un	
Current sense amplifier section	on l		İ	İ	1	<del>†                                    </del>	
Common mode rejection	CMRR	11 V < V <sub>CM</sub> < 12 V	4, 5, 6	60		i dB	
Power supply rejection	   PSRR 	8 V <u>&lt;</u> V <sub>IN</sub> <u>&lt;</u> 40 V	4, 5, 6	60		dB	
Input bias current	IIB	V(CUR LIM/SS pin) = 0.5 V COMP pin open 3/	1, 2, 3	-10		μА	
		V(CUR LIM/SS pin) = 0.5 V		<del>                                     </del>	1		
Input offset current	110	COMP pin open <u>3</u> / 	1, 2, 3	-1.0	1.0	μА	
Delay to outputs 2/		T <sub>A</sub> = +25°C	9	!	500	ns	
Current limit adjust section		V(-CUR SENSE pin) = 0 V		<del> </del>	, , ,	<u> </u>	
Current limit offset		V(+CUR SENSE pin) = 0 V COMP pin open 3/	1, 2, 3	0.40	0.55	V d	
Input bias current	i-IB	V(+ERROR AMP pin) = VREF $V(-ERROR AMP pin) = 0 V$	1, 2, 3	-30		μА	
Shutdown terminal section				-			
Threshold voltage			1, 2, 3	250	400	mV	
Latching voltage	<del>                                     </del>	Current into CUR LIM/SS pin = 3.0 mA <u>5</u> /			2.0	V d	
Nonlatching voltage		Current into CUR LIM/SS pin = 0.8 mA <u>6</u> /		5.0		V d	
Delay to outputs 2/		T <sub>A</sub> = +25°C	1	į	600	ns	
utput section			i	i			
Collector-emitter voltage	! ! !		1, 2, 3	40	İ	V do	
Collector leakage current	 	V <sub>C</sub> = 40 V <u>7</u> /	1, 2, 3		200	μΑ с	
ee footnotes at end of table.				1			
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TABLE I.	Electrica	al performance characteristics -	Continued.			
Test	  Symbol 		  Group A  subgroups	i -	mits   Max	   Unit 
Output low level	VOL		1, 2, 3		0.4	V dc
Output high level	V <sub>OL</sub>	I <sub>SOURCE</sub> = 20 mA  I <sub>SOURCE</sub> = 100 mA	1, 2, 3	13 12	i   	V dc
Output section - Continued  Rise time 2/	    t <sub>r</sub>	  C <sub>L</sub> = 1,000 pF T <sub>A</sub> = +25°C	9		300	ns
Fall time 2/	tf	  C <sub>L</sub> = 1,000 pF T <sub>A</sub> = +25°C	9		300	ns
Under-voltage lockout section Start-up threshold			1, 2, 3	l	8.0	V dc
Total standby current Supply current	Icc		1, 2, 3		21	mA do
Cold start/PWM latch reset	L <sub>reset</sub>	T <sub>J</sub> = -55°C, R <sub>T</sub> = 10 kΩ,  C <sub>T</sub> = 4700 pF,  SYNC I <sub>OUT</sub> = -1 mA	3	<u>8</u> /		kHz

Standard test conditions (unless otherwise specified):  $+V_{IN} = 15 \text{ V}$  dc,  $R_T = 10 \text{ k}\Omega$ ;  $C_T = 4,700 \text{ pF}$ . If not tested, shall be guaranteed to specified limits. Parameter measured at trip point of latch with  $V_{+ERROR}$  AMP=  $V_{REF}$ ;  $V_{-ERROR}$  AMP=  $V_{-ERROR$ 

Amplifier gain defined as:

$$G = \frac{\Delta^{V}COMP \ pin}{\Delta^{V}+CURRENT \ SENSE \ pin} = 0 \ to \ 1.0 \ V$$

Current into CUR LIM/SS pin guaranteed to latch circuit in shutdown state.

Current into CUR LIM/SS pin guaranteed not to latch circuit in shutdown state.

This parameter only applies to device type 01.

To verify that the PWM latch is resetting properly, the output stage must resume switching after the completion of a PWN latch Set command. To minimize the effects of self heating, the test must be completed within the first 50 milliseconds of applied power. The minimum limit shall be equal to 0.49 x the oscillator frequency.

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- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 Verification and review. DESC, DESC's agent and the acquiring activity reserve the right to retain the option to review the manufacturer's facility and applicable required documentation. Off-shore documentation shall be made available on-shore at the option of the reviewer.
  - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
  - a. Burn-in test, method 1015 of MIL-STD-883.
    - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
    - (2)  $T_A = +125^{\circ}C$ , minimum.
  - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method  $\overline{5005}$  of MIL-SID-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
  - 4.3.1 Group A inspection.
    - a. Tests shall be as specified in table II herein.
    - b. Subgroups 7, 8, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.
  - 4.3.2 Groups C and D inspections.
    - a. End-point electrical parameters shall be as specified in table II herein.
    - b. Steady-state life test conditions, method 1005 of MIL-STD-883.
      - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
      - (2)  $T_A = +125^{\circ}C$ , minimum.
      - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	1
Final electrical test parameters (method 5004)	1*,2,3,4,9
Group A test requirements (method 5005)	1,2,3,4,5,6,9
Groups C and D end-point electrical parameters (method 5005)	1,2,3

<sup>\*</sup>PDA applies to subgroup 1.

## 5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

# 6. NOTES

- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

# STANDARDIZED MILITARY DRAWING

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6.4 Approved source of supply. Approved sources of supply are listed herein. Additional sources will be added as they become available. The vendors listed herein have agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing   part number	Vendor     CAGE     number	Vendor   similar part   number <u>1</u> /		
5962-8680601EX	12969   64155   34333	UC1846J/883B LT1846J/883B SG1846J/883B		
5962-8680601FX	34333	SG1846F/883B		
5962-86806012X	12969     34333	UC1846L/883B SG1846L/883B		
5962-8680602EX	34333   12969   64155	SG1847J/883B UC1847J/883B LT1847J/883B		
5962-8680602FX	34333	SG1847F/883B		
5962-86806022X	12969   34333	UC1847L/883B SG1847L/883B		

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number	Vendor name and address
12969	Unitrode Corporation 5 Forbes Road Lexington, MA 02173
34333	Silicon General, Incorporated 11861 Western Avenue Garden Grove, CA 92641
64155	Linear Technology Corporation 1630 McCarthy Boulevard Milpitas. CA 95035-7487

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